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2020-10-28

MARSH DOMINIK

17th International Workshop on the Physics of Semiconductor Devices 2013
CRC Press

This book addresses material growth, device fabrication, device application, and commercialization of energy-efficient white light-emitting diodes (LEDs), laser diodes, and power electronics devices. It begins with an overview on basics of semiconductor materials, physics, growth and characterization techniques, followed by detailed discussion of advantages, drawbacks, design issues, processing, applications, and key challenges for state of the art GaN-based devices. It includes state of the art material synthesis techniques with an overview on growth technologies for emerging bulk or free standing GaN and AlN substrates and their applications in electronics, detection, sensing, optoelectronics and photonics. Wengang (Wayne) Bi is Distinguished Chair Professor and Associate Dean in the College of Information and Electrical Engineering at Hebei University of Technology in Tianjin, China. Hao-chung (Henry) Kuo is Distinguished Professor and Associate Director of the Photonics Center at National Chiao-Tung University, Hsin-Tsu, Taiwan, China. Pei-Cheng Ku is an associate professor in the Department of Electrical Engineering & Computer Science at the University of Michigan, Ann Arbor, USA. Bo Shen is the Cheung Kong Professor at Peking University in China.

Recent Developments in Superconductivity Research CRC Press

Optics and photonics offer new and vibrant approaches to meeting the challenges of the 21st century concerning energy conservation, education, agriculture, personal health and the environment. One of the most effective ways to address these global problems is to provide updated and reliable content on light-based technologies. Optical thin films and meta-materials, lasers, optical communications, light-emitting diodes, solar cells, liquid crystal technology, nanophotonics and biophotonics all play vital roles in enriching our lives. We hope

to raise readers' awareness of how optical technologies are now promoting sustainable development and providing reliable solutions to basic human needs. Furthermore, in order to broaden new research fields, we hope to inspire them to pursue further cutting-edge breakthroughs on the basis of the accomplishments that have already been made.

Gallium Arsenide, Electronics Materials and Devices. A Strategic Study of Markets, Technologies and Companies Worldwide 1999-2004 Recent Developments in Superconductivity Research

This book is an introduction to the fundamentals of emerging non-volatile memories and provides an overview of future trends in the field. Readers will find coverage of seven important memory technologies, including Ferroelectric Random Access Memory (FeRAM), Ferromagnetic RAM (FMRAM), Multiferroic RAM (MFRAM), Phase-Change Memories (PCM), Oxide-based Resistive RAM (RRAM), Probe Storage, and Polymer Memories. Chapters are structured to reflect diffusions and clashes between different topics. Emerging Non-Volatile Memories is an ideal book for graduate students, faculty, and professionals working in the area of non-volatile memory. This book also: Covers key memory technologies, including Ferroelectric Random Access Memory (FeRAM), Ferromagnetic RAM (FMRAM), and Multiferroic RAM (MFRAM), among others. Provides an overview of non-volatile memory fundamentals. Broadens readers' understanding of future trends in non-volatile memories.

Two-step MOVPE, in-situ etching and buried implantation: applications to the realization of GaAs laser diodes John Wiley & Sons

The Institute of Physics Conference Series is a leading International medium for the rapid publication of proceedings of major conferences and symposia reviewing new developments in physics and related areas. Volumes in the series comprise original refereed papers and are regarded as standard referee works. As such, they are an essential part of major libration collections worldwide. The twelfth conference on the Microscopy of

Semiconducting Materials (MSM) was held at the University of Oxford, 25-29 March 2001. MSM conferences focus on recent international advances in semiconductor studies carried out by all forms of microscopy. The event was organized with scientific sponsorship by the Royal Microscopical Society, The Electron Microscopy and Analysis Group of the Institute of Physics and the Materials Research Society. With the continual shrinking of electronic device dimensions and accompanying enhancement in device performance, the understanding of semiconductor microscopic properties at the nanoscale (and even at the atomic scale) is increasingly critical for further progress to be achieved. This conference proceedings provides an overview of the latest instrumentation, analysis techniques and state-of-the-art advances in semiconducting materials science for solid state physicists, chemists, and materials scientists.

Physics and Technology of High-k Gate Dielectrics 5 Springer Science & Business Media

In a uniform and comprehensive manner the authors describe all the important aspects of the epitaxial growth processes of solid films on crystalline substrates, e.g. processes in which atoms of the growing film mimic the arrangement of the atoms of the substrate. Emphasis is put on sufficiently fundamental and unequivocal presentation of the subject in the form of an easy-to-read review. A large part of this book focuses on the problems of heteroepitaxy. The most important epitaxial growth techniques which are currently widely used in basic research as well as in manufacturing processes of devices are presented and discussed in detail.

Epitaxy MDPI

This multidisciplinary book provides up-to-date coverage of carrier and spin dynamics and energy transfer and structural interaction among nanostructures. Coverage also includes current device applications such as quantum dot lasers and detectors, as well as future applications to quantum information processing. The book will

serve as a reference for anyone working with or planning to work with quantum dots.

Precursor Synthesis, Development and Applications The Electrochemical Society Systematically discusses the growth method, material properties, and applications for key semiconductor materials MOVPE is a chemical vapor deposition technique that produces single or polycrystalline thin films. As one of the key epitaxial growth technologies, it produces layers that form the basis of many optoelectronic components including mobile phone components (GaAs), semiconductor lasers and LEDs (III-Vs, nitrides), optical communications (oxides), infrared detectors, photovoltaics (II-IV materials), etc. Featuring contributions by an international group of academics and industrialists, this book looks at the fundamentals of MOVPE and the key areas of equipment/safety, precursor chemicals, and growth monitoring. It covers the most important materials from III-V and II-VI compounds to quantum dots and nanowires, including sulfides and selenides and oxides/ceramics. Sections in every chapter of Metalorganic Vapor Phase Epitaxy (MOVPE): Growth, Materials Properties and Applications cover the growth of the particular materials system, the properties of the resultant material, and its applications. The book offers information on arsenides, phosphides, and antimonides; nitrides; lattice-mismatched growth; CdTe, MCT (mercury cadmium telluride); ZnO and related materials; equipment and safety; and more. It also offers a chapter that looks at the future of the technique. Covers, in order, the growth method, material properties, and applications for each material Includes chapters on the fundamentals of MOVPE and the key areas of equipment/safety, precursor chemicals, and growth monitoring Looks at important materials such as III-V and II-VI compounds, quantum dots, and nanowires Provides topical and wide-ranging coverage from well-known authors in the field Part of the Materials for Electronic and Optoelectronic Applications series Metalorganic Vapor Phase Epitaxy (MOVPE): Growth, Materials Properties and Applications is an excellent book for graduate students, researchers in academia and industry, as well as specialist courses at undergraduate/postgraduate level in the area of epitaxial growth (MOVPE/ MOCVD/ MBE).

Physics of Semiconductor Devices CRC Press

The "blue laser" is an exciting new device

used in physics. The potential is now being recognized for its development into a commercial lighting system using about a tenth of the power and with a thousand times the operating lifetime of a comparable conventional system. This comprehensive work introduces the subject at a level suitable for graduate students. It covers the basics physics of light emitting diodes (LEDs) and laser diodes (LDs) based on gallium nitride and related nitride semiconductors, and gives an outline of their structural, transport and optical properties, and the relevant device physics. It begins with the fundamentals, and covers both theory and experiment, as well as an examination of actual and potential device applications. Shuji Nakamura and Nichia Chemicals Industries made the initial breakthroughs in the field, and these have revealed that LEDs and LDs are a sophisticated physical phenomenon and a commercial reality.

SISPAD 01 Cuvillier Verlag

This report examines the development of the diode laser industry over a six-year period, 2000 to 2005, incorporating analysis of trends in markets, technologies and industry structure. It is designed to provide key information to users and manufacturers of substrates, epitaxial wafers (epiwafers) and devices. The coverage includes components, laser diodes, and the semiconducting (SC) wafers and epiwafers on which most of these devices are made. The geographical coverage of the report includes North America, Japan and Europe, which together will account for over 90% of the production and consumption of diode laser materials and devices over the next five years. However, many other countries have activities in this field including South-East Asia (Taiwan, South Korea, Singapore, Malaysia etc), China, India, Australia and Eastern Europe (Russia, Poland, Hungary, the Czech Republic) amongst others.

Activities in these countries are commented on in the text where relevant, but are not quantified in the market data. Chapter 1 is an introduction to the market study. Chapter 2 contains an executive summary. Chapter 3 overviews materials markets. The size, quality, and particularly the price, of substrates and wafers are key factors in determining the ability of companies to produce competitive laser products. Chapter 3 also examines trends in materials technologies for laser diodes, the impact of the device markets on wafer demand, and the main suppliers. This chapter introduces the semiconductor materials that are presently or will likely become important to the fabrication of diode laser devices. The principal

distinguishing properties of these materials are explained with reference to their application. Chapter 4 chapter examines the basic application sectors for laser diode devices as well as the basic commercial opportunities, changes and forces acting within each sector. The chapter also examines the market for the basic types of device as well as the promising newer types. For each type of device, market data and forecasts are provided and future prospects described. The application data are presented for the following industrial groups: • Automotive • Computers • Consumer • Industrial • Military and Aerospace • Telecommunications • Others A full 5-year forecast and analysis is provided by application and region. Chapter 5 is a technology overview. In this chapter a background and overview of developments in the principal technological R&D and production processes for devices is provided. The main focus is on the most important enabling technology for the production of the present and future generations of laser diodes and related devices. This process is crystal growth and involves the following sequence: • Bulk growth of single crystals • Epitaxial growth of semiconductor single crystal layers • Ion implantation • Device fabrication, ie gate and contact formation, etc • Packaging & test Chapter 6 profiles substrate suppliers, epiwafers suppliers and merchant and captive producers of GaAs devices. Chapter 7 lists universities and selected industrial labs involved in the areas of diode laser research. Chapter 8 is a directory of suppliers. Chapter 9 provides acronyms and exchange rates. For a PDF version of the report please call Tina Enright on +44 (0) 1865 843008 for price details.

CVD of Compound Semiconductors CRC Press

Recent Developments in Superconductivity Research Nova Publishers

Chemical Vapor Deposition World Scientific

The purpose of this workshop is to spread the vast amount of information available on semiconductor physics to every possible field throughout the scientific community. As a result, the latest findings, research and discoveries can be quickly disseminated. This workshop provides all participating research groups with an excellent platform for interaction and collaboration with other members of their respective scientific community. This workshop's technical sessions include various current and significant topics for applications and scientific developments,

including • Optoelectronics • VLSI & ULSI Technology • Photovoltaics • MEMS & Sensors • Device Modeling and Simulation • High Frequency/ Power Devices • Nanotechnology and Emerging Areas • Organic Electronics • Displays and Lighting Many eminent scientists from various national and international organizations are actively participating with their latest research works and also equally supporting this mega event by joining the various organizing committees.

High Tc Superconductors

Forschungszentrum Jülich

The standard incandescent light bulb, which still works mainly as Thomas Edison invented it, converts more than 90% of the consumed electricity into heat. Given the availability of newer lighting technologies that convert a greater percentage of electricity into useful light, there is potential to decrease the amount of energy used for lighting in both commercial and residential applications. Although technologies such as compact fluorescent lamps (CFLs) have emerged in the past few decades and will help achieve the goal of increased energy efficiency, solid-state lighting (SSL) stands to play a large role in dramatically decreasing U.S. energy consumption for lighting. This report summarizes the current status of SSL technologies and products-light-emitting diodes (LEDs) and organic LEDs (OLEDs)-and evaluates barriers to their improved cost and performance.

Assessment of Advanced Solid State Lighting also discusses factors involved in achieving widespread deployment and consumer acceptance of SSL products. These factors include the perceived quality of light emitted by SSL devices, ease of use and the useful lifetime of these devices, issues of initial high cost, and possible benefits of reduced energy consumption.

Clean Electricity from Photovoltaics

McFarland

Chemical Vapour Deposition (CVD) involves the deposition of thin solid films from chemical precursors in the vapour phase, and encompasses a variety of deposition techniques, including a range of thermal processes, plasma enhanced CVD (PECVD), photon- initiated CVD, and atomic layer deposition (ALD). The development of CVD technology owes a great deal to collaboration between different scientific disciplines such as chemistry, physics, materials science, engineering and microelectronics, and the publication of this book will promote and stimulate continued dialogue between scientists from these different research areas. The book is one of the most

comprehensive overviews ever written on the key aspects of chemical vapour deposition processes and it is more comprehensive, technically detailed and up-to-date than other books on CVD. The contributing authors are all practising CVD technologists and are leading international experts in the field of CVD. It presents a logical and progressive overview of the various aspects of CVD processes. Basic concepts, such as the various types of CVD processes, the design of CVD reactors, reaction modelling and CVD precursor chemistry are covered in the first few chapters. Then follows a detailed description of the use of a variety CVD techniques to deposit a wide range of materials, including semiconductors, metals, metal oxides and nitrides, protective coatings and functional coatings on glass. Finally and uniquely, for a technical volume, industrial and commercial aspects of CVD are also discussed together with possible future trends, which is an unusual, but very important aspect of the book. The book has been written with CVD practitioners in mind, such as the chemist who wishes to learn more about CVD processes, or the CVD technologist who wishes to gain an increased knowledge of precursor chemistry. The volume will prove particularly useful to those who have recently entered the field, and it will also make a valuable contribution to chemistry and materials science lecture courses at undergraduate and postgraduate level. [Compound Semiconductors 1999](#) CRC Press

A wide range of progress in materials development [single crystals, ceramics, thin films, wire and tapes] is reported in the 169 papers in this volume. The main focus of the papers is in attaining a better understanding of the relationship between microstructure and electrical properties. Invited papers cover topics such as the effects of substitution and doping; multilayers; nanostructure characterisation; electric field effects in High Tc Superconductors [HTS]; surface stability; critical currents; flux pinning and magneto-optic imaging of flux patterns; effects of irradiation induced defects; properties and preparation of materials; microwave properties and electronic devices. A clearly broadened basis for understanding processes and mechanisms in [HTS] is portrayed. Appreciable progress has been achieved in the reproducible manufacturing of high quality materials supported by very efficient methods in microstructural analysis. This essential improvement is reflected in the increased number of practical devices encouraging

the use of HTS in applications for electronics and power engineering, all of which are reviewed in depth in this work. *Wide Bandgap Based Devices* Springer This book provides an overview of chemical vapor deposition (CVD) methods and recent advances in developing novel materials for application in various fields. CVD has now evolved into the most widely used technique for growth of thin films in electronics industry. Several books on CVD methods have emerged in the past, and thus the scope of this book goes beyond providing fundamentals of the CVD process. Some of the chapters included highlight current limitations in the CVD methods and offer alternatives in developing coatings through overcoming these limitations.

[Proceedings of IWPSD 2017](#) Elsevier

During the last decade, novel graphene related materials (GRMs), perovskites, as well as metal oxides and other metal nanostructures have received the interest of the scientific community. Due to their extraordinary physical, optical, thermal, and electrical properties, which are correlated with their 2D ultrathin atomic layer structure, large interlayer distance, ease of functionalization, and bandgap tunability, these nanomaterials have been applied in the development or the improvement of innovative optoelectronic applications, as well as the expansion of theoretical studies and simulations in the fast-growing fields of energy (photovoltaics, energy storage, fuel cells, hydrogen storage, catalysis, etc.), electronics, photonics, spintronics, and sensing devices. The continuous nanostructure-based applications development has provided the ability to significantly improve existing products and to explore the design of materials and devices with novel functionalities. This book demonstrates some of the most recent trends and advances in the interdisciplinary field of optoelectronics. Most articles focus on light emitting diodes (LEDs) and solar cells (SCs), including organic, inorganic, and hybrid configurations, whereas the rest address photodetectors, transistors, and other well-known dynamic optoelectronic devices. In this context, this exceptional collection of articles is directed at a broad scientific audience of chemists, materials scientists, physicists, and engineers, with the goals of highlighting the potential of innovative optoelectronic applications incorporating nanostructures and inspiring their realization.

Semiconductor Materials The Electrochemical Society

Superconductivity is the ability of certain

materials to conduct electrical current with no resistance and extremely low losses. High temperature superconductors, such as $\text{La}_{2-x}\text{Sr}_x\text{CuO}_x$ ($T_c=40\text{K}$) and $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ ($T_c=90\text{K}$), were discovered in 1987 and have been actively studied since. In spite of an intense, world-wide, research effort during this time, a complete understanding of the copper oxide (cuprate) materials is still lacking. Many fundamental questions are unanswered, particularly the mechanism by which high- T_c superconductivity occurs. More broadly, the cuprates are in a class of solids with strong electron-electron interactions. An understanding of such "strongly correlated" solids is perhaps the major unsolved problem of condensed matter physics with over ten thousand researchers working on this topic. High- T_c superconductors also have significant potential for applications in technologies ranging from electric power generation and transmission to digital electronics. This ability to carry large amounts of current can be applied to electric power devices such as motors and generators, and to electricity transmission in power lines. For example, superconductors can carry as much as 100 times the amount of electricity of ordinary copper or aluminium wires of the same size. Many universities, research institutes and companies are working to develop high- T_c superconductivity applications and considerable progress has been made. This volume brings together new leading-edge research in the field.

Precursors, Processes and Applications

World Scientific

Photovoltaic cells provide clean, reversible electrical power from the sun. Made from semiconductors, they are durable, silent in operation and free of polluting emissions.

In this book, experts from all sectors of the PV community — materials scientists, physicists, production engineers, economists and environmentalists — give their critical appraisals of where the technology is now and what its prospects are. Contents: The Past and Present (M D Archer) Device Physics of Silicon Solar Cells (J O Schumacher & W Wettling) Principles of Cell Design (J Poortmans et al.) Crystalline Silicon Solar Cells (M A Green) Amorphous Silicon Solar Cells (C R Wronski & D E Carlson) Cadmium Telluride Solar Cells (D Bonnet) $\text{Cu}(\text{In},\text{Ga})\text{Se}_2$ Solar Cells (U Rau & H W Schock) Super-High Efficiency III-V Tandem and Multijunction Cells (M Yamaguchi) Organic Photovoltaic Devices (J J M Halls & R H Friend) Quantum Well Solar Cells (J Nelson) Thermophotovoltaic Generation of Electricity (T J Coutts) Concentrator Cells and Systems (A Luque) Cells and Systems for Space Applications (C M Hardingham) Storage of Electrical Energy (R M Dell) Photovoltaic Modules, Systems and Applications (N M Pearsall & R Hill) The Photovoltaic Business: Manufacturers and Markets (B McNelis) The Economics of Photovoltaic Technologies (D Anderson) The Outlook for PV in the 21st Century (E H Lysen & B Yordi) Readership: Physicists, chemists and engineers. Keywords: Electricity; Photovoltaics; Cadmium; Solar Cells Reviews: "... is an excellent resource for its intended readership of students, scientists and technologists working in the area ... it is well indexed, and includes a handy list of useful web and library references. At the very least, the book deserves a place in the library of every research institution and company working on renewable energy." Nature "With a broad range of coverage, many

references in each chapter, and an appendix listing useful quantities, factors and symbols, this book would be an excellent reference source for any one working in the field of photovoltaics." IEEE Electrical Insulation Magazine "It is timely, up-to-date and a very comprehensive work. The chapters are written by leading experts in their field who are able to communicate the technology and their enthusiasm ... Photovoltaic R&D is a multi-disciplinary activity, and most chapters should be accessible to advanced undergraduate students, postgraduates and researchers with a wide range of backgrounds. It can be recommended to those starting a PhD in the area and to existing researchers in other fields who wish to find out what all the excitement is about." Contemporary Physics *Proceedings of the 26th International Symposium on Compound Semiconductors, 23-26th August 1999, Berlin, Germany* National Academies Press The third edition of this highly respected market study provides a detailed insight into the global developments of the GaAs industry to 2004, and the implications for both suppliers and users of GaAs technology. The report has been completely revised and updated with a new chapter added on competitive technologies. The report also supplies market analysis by component type and application sectors. For a PDF version of the report please call Tina Enright on +44 (0) 1865 843008 for price details. Nova Publishers The book presents invited reviews and original short notes with recent results obtained in fabrication study and application of nanostructures, which are promising for new generations of electronic and optoelectronic devices.